#### TOSHIBA VARIABLE CAPACITANCE DIODE SILICON EPITAXIAL PLANAR TYPE

## 1 S V 2 6 9

CATV TUNING.

High Capacitance Ratio : C2V/C25V = 11.5 (Typ.)

Low Series Resistance :  $rs = 0.55\Omega$  (Typ.)

Excellent C-V Characteristics, and Small Tracking Error.

Small Package

#### MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Reverse Voltage	$v_{ m R}$	34	V
Peak Reverse Voltage	$ m v_{RM}$	$36  (R_L = 10 \mathrm{k}\Omega)$	V
Junction Temperature	$\mathrm{T_{j}}$	125	$^{\circ}\mathrm{C}$
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~125	$^{\circ}\mathrm{C}$

# Unit in mm $^{+\,0.2}_{1.25\,-\,0.1}$ CATHODE MARK $0 \pm 0.05$ 0.3 - 0.05 $0.15 \, {}^{+\, 0.1}_{-\, 0.06}$ **JEDEC EIAJ** TOSHIBA 1-1E1A

### ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Reverse Voltage	$V_{\mathbf{R}}$	$I_R = 1 \mu A$	34		_	V
Reverse Current	$I_{ m R}$	$V_{ m R}\!=\!32V$			10	nA
Capacitance	C2V	$V_R = 2V$ , $f = 1MHz$	29	31.5	34	рF
Capacitance	C25V	$V_R = 25V$ , $f = 1MHz$	2.5	2.75	2.9	рF
Capacitance Ratio	C2V / C25V	<del>-</del>	11.0	11.5	_	_
Capacitance Ratio	C25V / C28V	<del>-</del>	1.03	1.05	_	_
Series Resistance	$ m r_{S}$	$V_R = 5V$ , $f = 470MHz$	_	0.55	0.7	Ω

Note 1: Available in matched group for capacitance to 2.0%.

$$\frac{C \text{ (Max.)} - C \text{ (Min.)}}{C \text{ (Min.)}} \le 0.02 \text{ (VR} = 2 \sim 25 \text{V)}$$

Marking



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